

NSN 5961-01-014-9704 Thyristor Semiconductor Device - Page 1 of 1
Thynstor Semiconductor Device - Tage Tor T
View Online at https://aerobasegroup.com/nsn/5961-01-014-9704
Inclosure Material:
Glass and metal
Overall Length:
0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.230 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
30.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
6.00 amperes forward current, average preset
Power Rating Per Characteristic:
100.0 milliwatts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
110.0 degrees celsius junction
Special Features:
Internal junction configuration arrangement pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0